2SCR502EB / 2SCR502UB

NPN 500mA 30V General purpose transistors

Datasheet

| Parameter | Value |
|------------------|-------|
| V _{CEO} | 30V |
| I _C | 0.5A |

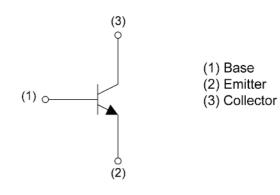
Outline



Features

- 1)General purpose.
- 2)Complementary PNP types : 2SAR502EB(EMT3F)/2SAR502UB(UMT3F)
- 3)Collector current is large.
- 4)Low V_{CE(sat)}.

•Inner circuit



Application

LOW FREQUENCY AMPLIFIER

Packaging specifications

| Part No. | Package | Package size | Taping code | Reel size (mm) | Tape width (mm) | Basic ordering unit.(pcs) | Marking |
|-----------|---------|-----------------|----------------|-------------------|-----------------|---------------------------------|---------|
| 2SCR502EB | EMT3F | 1616 | TL | 180 | 8 | 3000 | LW |
| 2SCR502UB | UMT3F | 2021 | TL | 180 | 8 | 3000 | LW |

● Absolute maximum ratings (T_a = 25°C)

| Parameter | | | Values | Unit | |
|------------------------------|---------------------|-------------------|-------------|------|--|
| Collector-base voltage | | V_{CBO} | 30 | V | |
| Collector-emitter voltage | | V _{CEO} | 30 | V | |
| Emitter-base voltage | | V _{EBO} | 6 | V | |
| Calla atau accumant | ellector current | | 0.5 | Α | |
| Collector current | | | 1 | Α | |
| Base current | Base current | | | Α | |
| Davis a dissination | 2SCR502EB | P _D *3 | 150 | mW | |
| Power dissipation | 2SCR502UB | P _D ° | 200 | | |
| Junction temperature | unction temperature | | 150 | °C | |
| Range of storage temperature | | T _{stg} | -55 to +150 | °C | |

● Electrical characteristics (T_a = 25°C)

| Darameter | Symbol | Conditions | Values | | | Unit | |
|--------------------------------------|-------------------------|---|--------|------|------|-------|--|
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | UIIIL | |
| Collector-base breakdown voltage | BV _{CBO} | I _C = 100μA | 30 | 1 | 1 | V | |
| Collector-emitter breakdown voltage | BV _{CEO} | I _C = 1mA | 30 | 1 | 1 | V | |
| Emitter-base breakdown voltage | BV _{EBO} | I _E = 100μA | 6 | 1 | 1 | ٧ | |
| Collector cut-off current | I _{CBO} | V _{CB} = 25V | - | 1 | 200 | nA | |
| Emitter cut-off current | I _{EBO} | V _{EB} = 4V | - | - | 200 | nA | |
| Collector-emitter saturation voltage | V _{CE(sat)} *4 | I _C = 200mA, I _B = 10mA | - | 100 | 300 | mV | |
| DC current gain | h _{FE} | $V_{CE} = 2V, I_{C} = 100 \text{mA}$ | 200 | 1 | 500 | - | |
| Transition frequency | f _T *4 | $V_{CE} = 10V, I_{E} = -100mA,$ f = 100MHz | - | 360 | - | MHz | |
| Output capacitance C | | $V_{CB} = 10V$, $I_E = 0A$, $f = 1MHz$ | - | 3 | - | pF | |

^{*1} Limited by power dissipation.

^{*2} Pw=10ms, Single pulse.

^{*3} Each terminal mounted on a reference land.

^{*4} Pulsed

● Electrical characteristic curves(T_a = 25°C)

Fig.1 Grounded Emitter Propagation Characteristics

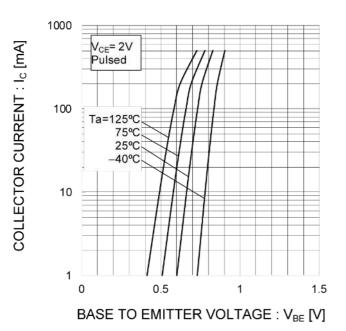
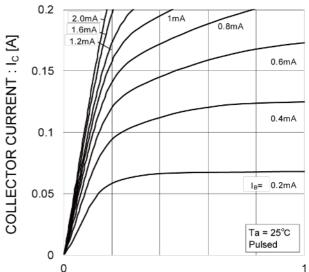


Fig.2 Typical Output Characteristics



COLLECTOR TO EMITTER VOLTAGE: V_{CE} [V]

Fig.3 DC Current Gain vs. Collector Current(I)

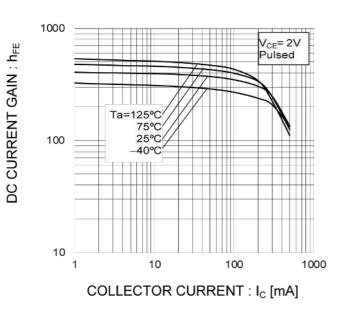
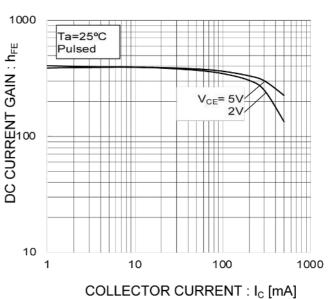


Fig.4 DC Current Gain vs. Collector Current(II)



● Electrical characteristic curves(T_a = 25°C)

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current(I)

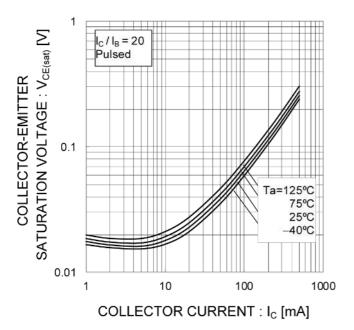


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current(II)

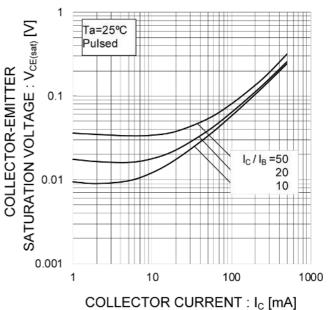


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

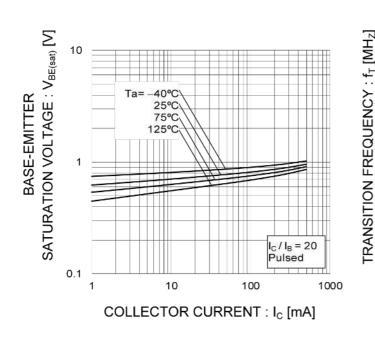
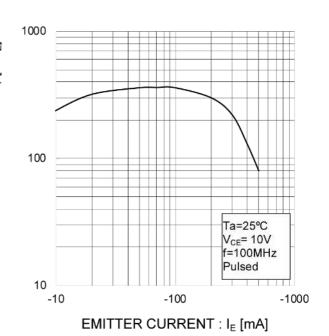


Fig.8 Gain Bandwidth Product vs. Emitter Current



● Electrical characteristic curves(T_a = 25°C)

Fig.9 Emitter input capacitance vs. Emitter-Base Voltage Collector output capacitance vs. Collector-Base Voltage

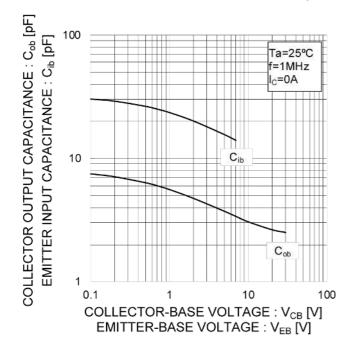


Fig.10 Safe Operating Area

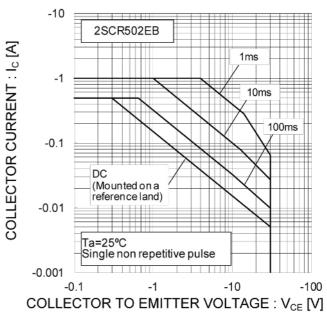
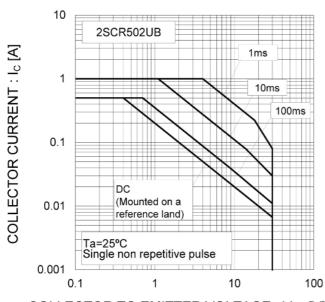
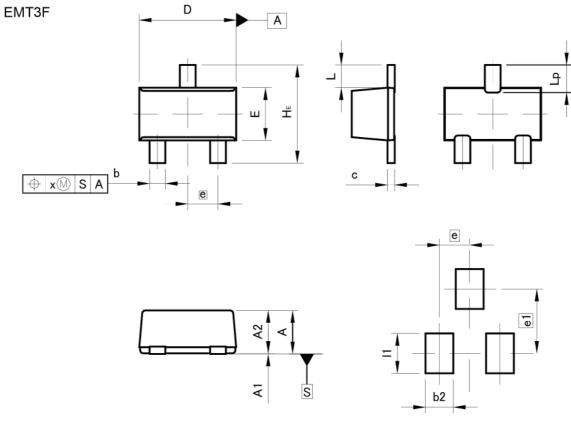


Fig.11 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE: VCE [V]

Dimensions



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

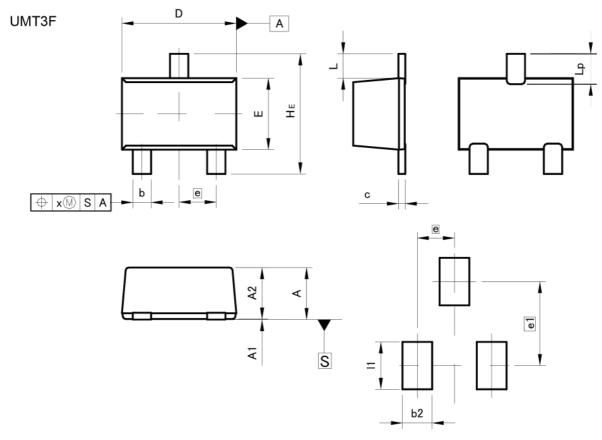
| DIM | MILIM | ETERS | INCHES | | |
|-----|-------|-------|--------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 0.65 | 0.85 | 0.026 | 0.033 | |
| A1 | 0.00 | 0.10 | 0.000 | 0.004 | |
| A2 | 0.60 | 0.80 | 0.024 | 0.031 | |
| b | 0.21 | 0.36 | 0.008 | 0.014 | |
| С | 0.08 | 0.18 | 0.003 | 0.007 | |
| D | 1.50 | 1.70 | 0.059 | 0.067 | |
| E | 0.76 | 0.96 | 0.030 | 0.038 | |
| е | 9.0 | 50 | 0.0 | 20 | |
| HE | 1.50 | 1.70 | 0.059 | 0.067 | |
| L | 0.37 | | 0.0 | 15 | |
| Lp | 0.35 | 0.55 | 0.014 | 0.022 | |
| х | = | 0.10 | 1775 | 0.004 | |

| DIM - | MILIMETERS | | INCHES | |
|-------|------------|------|--------|-------|
| DIM | MIN | MAX | MIN | MAX |
| b2 | - | 0.46 | - | 0.018 |
| e1 | | 1.05 | | 0.041 |
| 11 | - | 0.65 | - | 0.026 |

Dimension in mm/inches



Dimensions



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

| DIM | MILIM | ETERS | INCHES | | |
|-----|-------|-------|--------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 0.85 | 1.05 | 0.033 | 0.041 | |
| A1 | 0.00 | 0.10 | 0.000 | 0.004 | |
| A2 | 0.80 | 1.00 | 0.031 | 0.039 | |
| b | 0.27 | 0.42 | 0.011 | 0.017 | |
| С | 0.08 | 0.18 | 0.003 | 0.007 | |
| D | 1.90 | 2.10 | 0.075 | 0.083 | |
| E | 1.15 | 1.35 | 0.045 | 0.053 | |
| е | 0.0 | 65 | 0.0 | 26 | |
| HE | 2.00 | 2.20 | 0.079 | 0.087 | |
| L | 0.43 | | 0.0 | 17 | |
| Lp | 0.43 | 0.63 | 0.017 | 0.025 | |
| х | | 0.10 | _ | 0.004 | |

| DIM | MILIMETERS | | INCHES | |
|-----|----------------|------|--------|-------|
| DIM | MIN | MAX | MIN | MAX |
| b2 | - : | 0.52 | _ | 0.020 |
| e1 | 1. | 1.47 | | 058 |
| 11 | - | 0.83 | - | 0.033 |

Dimension in mm/inches



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